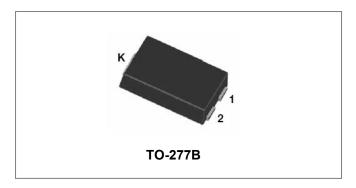


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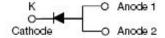
# **MBR560S SCHOTTKY RECTIFIER**



#### **Features**

- Designed as Bypass Diodes for Solar Panels
- High Forward Surge Capability
- Ultra Low Forward Voltage Drop
- Excellent High Temperature Stability
- This is a Halogen Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

# **Circuit Diagram**



## **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

#### **Maximum Ratings:**

| Characteristics  | Symbol   | Condition                                      | Max. | Units |
|--|--|--|------|-------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage | V <sub>RRM</sub><br>V <sub>RWM</sub><br>V <sub>R</sub> | -  | 60   | V     |
| Average Rectified Forward Current  | I <sub>F (AV)</sub>                                    | 50% duty cycle @Tc=80°C, rectangular wave form | 5    | Α     |
| Peak One Cycle Non-Repetitive Surge<br>Current   | I <sub>FSM</sub>                                       | 8.3ms, Half Sine pulse, Tc=25°C                | 120  | А     |

#### **Electrical Characteristics:**

| Characteristics        | Symbol          | Condition  | Тур. | Max. | Units |
|------------------------|-----------------|--|------|------|-------|
| Forward Voltage Drop * | V <sub>F1</sub> | @ 5A, Pulse, T <sub>J</sub> = 25 °C                        | 0.62 | 0.67 | V     |
|                        | V <sub>F2</sub> | @ 5A, Pulse, T <sub>J</sub> = 125 °C                       | 0.56 | -    | V     |
| Reverse Current*       | I <sub>R1</sub> | $@V_R = \text{rated } V_R$<br>$T_J = 25  ^{\circ}\text{C}$ | -    | 0.15 | mA    |
|                        | I <sub>R2</sub> | $@V_R = \text{rated } V_R$<br>$T_J = 125^{\circ}C$         | 15   | -    | mA    |

 $<sup>^*</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2%



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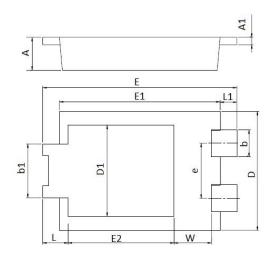




## **Thermal-Mechanical Specifications:**

| Characteristics  | Symbol            | Condition    | Specification | Units |
|--|-------------------|--------------|---------------|-------|
| Junction Temperature                                   | TJ                | -            | -55 to +150   | °C    |
| Storage Temperature                                    | T <sub>stg</sub>  | -            | -55 to +150   | °C    |
| Typical Thermal Resistance Junction to Soldering Point | R <sub>0</sub> JS | DC operation | 1.5           | °C/W  |
| Typical Thermal Resistance Junction to Case            | R <sub>0</sub> JC | DC operation | 2.3           | °C/W  |
| Approximate Weight                                     | wt                | -            | 0.08          | g     |

## **Mechanical Dimensions TO-277B**





| SYMBOL | Millimeters |      | Inches |       |  |
|--------|-------------|------|--------|-------|--|
|        | Min.        | Max. | Min.   | Max.  |  |
| Α      | 0.95        | 1.25 | 0.037  | 0.049 |  |
| A1     | 0.20        | 0.30 | 0.008  | 0.012 |  |
| b      | 0.85        | 0.95 | 0.033  | 0.037 |  |
| b1     | 1.70        | 1.90 | 0.067  | 0.075 |  |
| D      | 3.88        | 4.08 | 0.153  | 0.161 |  |
| D1     | 2.90        | 3.20 | 0.114  | 0.126 |  |
| е      | 1.74        | 1.94 | 0.069  | 0.076 |  |
| E      | 6.30        | 6.70 | 0.248  | 0.264 |  |
| E1     | 5.28        | 5.48 | 0.208  | 0.216 |  |
| E2     | 3.40        | 3.70 | 0.134  | 0.146 |  |
| L      | 0.70        | 1.00 | 0.028  | 0.039 |  |
| L1     | 0.41        | 0.71 | 0.016  | 0.028 |  |
| W      | 1.10        | 1.40 | 0.043  | 0.055 |  |

# **Ordering Information**

| Device  | Package          | Shipping      |  |
|---------|------------------|---------------|--|
| MBR560S | TO-277B(Pb-Free) | 5000pcs/ reel |  |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# **Marking Diagram**



Where XXXXX is YYWWL

5 = Forward Current (5A)
60 = Reverse Voltage (60V)
S = Package type
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •

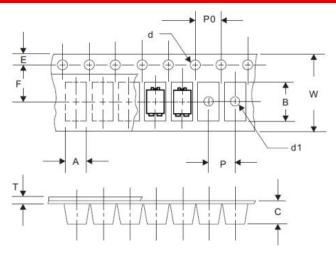


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#### Carrier Tape Specification TO-277B



| SYMBOL  | Millimeters |       |  |
|---------|-------------|-------|--|
| STIMBOL | Min.        | Max.  |  |
| Α       | 4.28        | 4.48  |  |
| В       | 6.80        | 7.10  |  |
| С       | 1.30        | 1.50  |  |
| d       | 1.40        | 1.60  |  |
| d1      | -           | 1.50  |  |
| E       | 1.65        | 1.85  |  |
| F       | 5.40        | 5.60  |  |
| Р       | 7.90        | 8.10  |  |
| P0      | 3.90        | 4.10  |  |
| Т       | 0.24        | 0.44  |  |
| W       | 11.70       | 12.30 |  |

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